## NSN 5962-01-263-6060

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View Online at https://aerobasegroup.com/nsn/5962-01-263-6060

Body Length:
1.220 inches
Body Width:
0.520 inches
Body Height:
0.180 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and bidirectional and w/decoded output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
22 input
Criticality Code Justification:
Zzzy
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Ram
Memory Capacity:
Unknown
Special Features:
Item must comply with requirements of defense supply center columbus production standard no. Lo3803
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Reference Number Differentiating Characteristics:

Reference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing

Shelf Life:

N/a

and testing specifications available at the dla icp

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Demilitarization:

Yes - demil/mli

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